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SNAS450B - JUNE 2008-REVISED MAY 2013

# LM48861 Boomer® Audio Power Amplifier Series Ground-Referenced, Ultra Low Noise, Stereo Headphone Amplifier

Check for Samples: LM48861, LM48861TMBD

#### **FEATURES**

- Ground Referenced Outputs Eliminates Output Coupling Capacitors
- Common-Mode Sensing
- Advanced Click-and-Pop Suppression
- Low Supply Current
- Minimum External Components
- Micro-Power Shutdown
- ESD Protection of 8kV HBM Contact
- Available in Space-Saving 12-Bump DSBGA Package

#### **APPLICATIONS**

- Mobile Phones
- Portable Electronic Devices
- MP3 Players

#### **KEY SPECIFICATIONS**

- Output Power/Channel at V<sub>DD</sub> = 1.5V,THD+N = 1%
  - $-R_L = 16\Omega 12mW (typ)$
  - $-R_L = 32\Omega 13mW (typ)$
- Output Power/Channel at V<sub>DD</sub> = 1.8V, THD+N = 1%
  - $-R_L = 16\Omega 24mW (typ)$
  - $R_1 = 32\Omega 22mW (typ)$
- Quiescent Power Supply Current at 1.5V 2mA (typ)
- PSRR at 217Hz 83dB (typ)
- Shutdown Current 0.01µA (typ)

#### DESCRIPTION

The LM48861 is a single supply, ground-referenced stereo headphone amplifier. Part of Tl's PowerWise™ product family, the LM48861 consumes only 3mW of power, yet still provides great audio performance. The ground-referenced architecture eliminates the larger DC blocking capacitors required by traditional headphone amplifier's saving board space and reducing cost.

The LM48861 features common-mode sensing that corrects for any differences between the amplifier ground and the potential at the headphone return terminal, minimizing noise created by any ground mismatches.

The LM48861 delivers 22mW/channel into a  $32\Omega$  load with <1% THD+N with a 1.8V supply. Power supply requirements allow operation from 1.2V to 2.8V. High power supply rejection ratio (PSRR), 83dB at 217Hz, allows the device to operate in noisy environments without additional power supply conditioning. A low power shutdown mode reduces supply current consumption to  $0.01\mu A$ .

Superior click and pop suppression eliminates audible transients on power-up/down and during shutdown. The LM48861 is available in an ultra-small 12-bump, 0.4mm pitch, DSBGA package (1.215mm x 1.615mm).

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## **Typical Application**

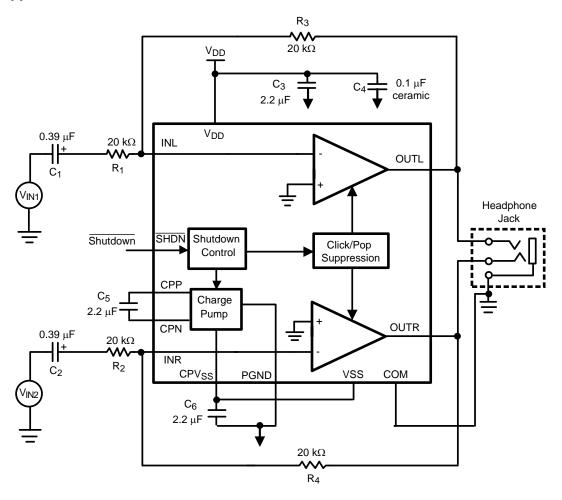


Figure 1. Typical Audio Amplifier Application Circuit



#### **Connection Diagrams**

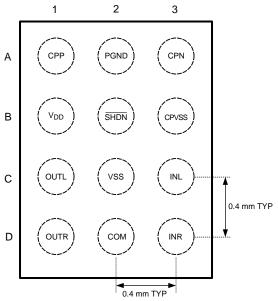


Figure 2. YFQ Package 1.215mm x 1.615mm x 0.6mm Top View See Package Number YFQ0012AAA

#### **BUMP DESCRIPTION**

Bump	Name	Description				
A1	CPP	Charge Pump Flying Capacitor Positive Terminal				
A2	PGND	Power Ground				
А3	CPN	Charge Pump Flying Capacitor Negative Terminal				
B1	$V_{DD}$	Positive Power Supply				
B2	SHDN	Active Low Shutdown				
В3	CPV <sub>SS</sub>	Charge Pump Output				
C1	OUTL	Left Channel Output				
C2	V <sub>SS</sub>	Negative Power Supply				
C3	INL	Left Channel Input				
D1	OUTR	Right Channel Output				
D2	СОМ	Ground reference for inputs and HP				
D3	INR	Right Channel Input				



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



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### Absolute Maximum Ratings (1)(2)(3)

Supply Voltage <sup>(1)</sup>		3V
Storage Temperature	−65°C to +150°C	
Input Voltage	-0.3V to V <sub>DD</sub> + 0.3V	
Power Dissipation (4)	Internally Limited	
ESD Ratings (HBM) <sup>(5)</sup>	2000V	
ESD Ratings(OUTL, OUTR) <sup>(5)</sup>	8000V	
ESD Susceptibility (Machine Model) (6)	200V	
Junction Temperature	150°C	
Thermal Resistance	θ <sub>JA</sub> (YFQ)	70°C/W (typ)

- (1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum RatingsRatings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified
- (2) The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.
- (3) If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.
- (4) Maximum allowable power dissipation is  $P_{DMAX} = (T_{JMAX} T_A) / \theta_{JA}$  or the number given in *Absolute Maximum Ratings*, whichever is lower
- (5) Human body model, applicable std. JESD22-A114C.
- (6) Machine model, applicable std. JESD22-A115-A.

### **Operating Ratings**

Temperature Range T <sub>MIN</sub> ≤ T <sub>A</sub> ≤ T <sub>MAX</sub>	-40°C ≤ T <sub>A</sub> ≤ +85°C
Supply Voltage (V <sub>DD</sub> )	$1.2V \le V_{DD} \le 2.8V$

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## Electrical Characteristics $V_{DD} = 1.5V^{(1)(2)}$

The following specifications apply for  $V_{DD}$  = 1.5V,  $A_V$  = -1V/V,  $R_L$  = 32k $\Omega$ , f = 1kHz, unless otherwise specified. Limits apply for  $T_A$  = 25°C.

	<b>.</b>	9 1111	LM4	18861	Units	
Symbol	Parameter	Conditions	Typical <sup>(3)</sup>	Limit <sup>(4)</sup>	(Limits)	
I <sub>DD</sub>	Quiescent Power Supply Current	V <sub>IN</sub> = 0V, Both channels enabled	2	2.8	mA (max)	
I <sub>SD</sub>	Shutdown Current	Shutdown Enabled V <sub>SHDN</sub> = GND	0.01	1.5	μA (max)	
V <sub>OS</sub>	Output Offset Voltage	$V_{IN} = 0V$ , $R_L = 32\Omega$ Both channels enabled	0.5	1.5	mV (max)	
$V_{IH}$	Shutdown Input Voltage High			1.4	V(min)	
$V_{IL}$	Shutdown Input Voltage Low			0.4	V(max)	
$T_WU$	Wake Up Time		500	700	μs (max)	
Po	Output Power	THD+N = 1% $R_L$ = 32 $\Omega$ , f = 1kHz, Both channels in phase and active $V_{DD}$ = 1.5V $V_{DD}$ = 1.8V	13 22	12 20	mW (min) mW (min)	
F0	Output Power	$THD+N = 1\% \ R_L = 16\Omega, \ f = 1kHz,$ Both channels in phase and active $V_{DD} = 1.5V$ $V_{DD} = 1.8V$	12 24		mW mW	
		$R_L = 10k\Omega$ , $f = 1kHz$			•	
V <sub>LINE-OUT</sub>	Output Voltage to Line Out	$V_{DD}$ = 1.5V, THD+N = 1%, $R_L$ = 10k $\Omega$	1.1	1	V <sub>RMS</sub> (min)	
		$V_{DD}$ = 1.8V, THD+N = 1%, $R_L$ = 10k $\Omega$	1.3	1.2	V <sub>RMS</sub> (min)	
		$P_O = 8mW$ , $f = 1kHz$ , $R_L = 32\Omega$	0.04		%	
THD+N	Total Harmonic Distortion + Noise	$P_O = 8mW$ , $f = 1kHz$ , $R_L = 16\Omega$	0.07		%	
		$V_{OLIF} = 900 \text{mV}_{RMS}, f = 1 \text{kHz}, R_L = 10 \text{k}\Omega$	0.001		%	
		$V_{RIPPLE} = 200 \text{mV}_{P-P}$ Sine, Inputs AC GND,	C1 = C2 = 0.39	μF		
PSRR	Power Supply Rejection Ratio	$f_{RIPPLE} = 217Hz$ $f_{RIPPLE} = 1kHz$ $f_{RIPPLE} = 15kHz$	83 77 57		dB dB dB	
SNR	Signal-to-Noise Ratio	$R_L = 32\Omega$ , $P_{OUT} = 8mW$ (A-weighted), $f = 1kHz$ BW = 20Hz to $22kHz$	102		dB	
X <sub>TALK</sub>	Crosstalk	$R_L = 32\Omega$ , $P_{OUT} = 5$ mW, $f = 1$ kHz	93		dB	
N <sub>OUT</sub>	Output Noise	A-weighted, $A_V = 5.1 dB$ R1 = R2 = 10kΩ, R3 = R4 = 18kΩ	5		μV	
C-P	Click-Pop	Inputs Grounded BW = <10Hz to >500kHz	79		dB	

<sup>(1) &</sup>quot;Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum RatingsRatings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified

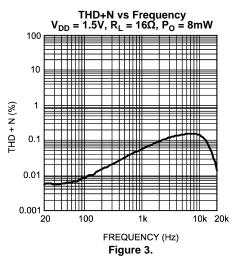
(4) Datasheet min/max specification limits are ensured by test or statistical analysis.

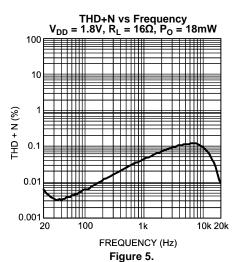
<sup>(2)</sup> The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.

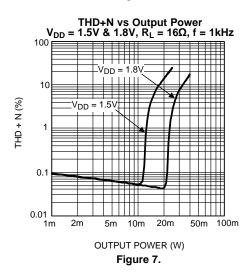
<sup>(3)</sup> Typical values represent most likely parametric norms at T<sub>A</sub> = +25°C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

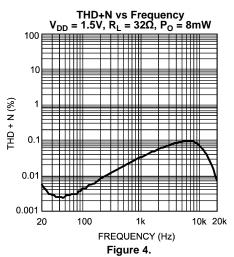


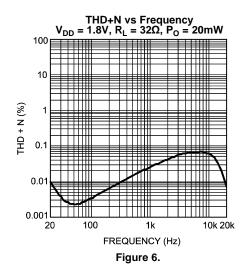
#### **Typical Performance Characteristics**

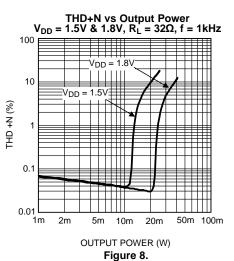














#### Typical Performance Characteristics (continued)

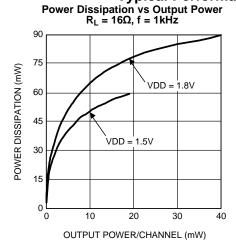


Figure 9.

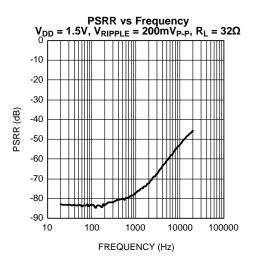
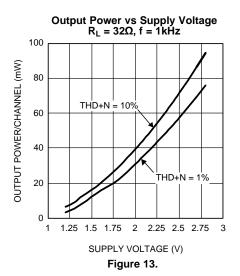
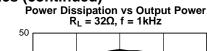


Figure 11.





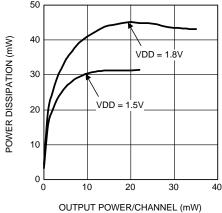


Figure 10.

## Output Power vs Supply Voltage $R_L = 16\Omega$ , f = 1kHz

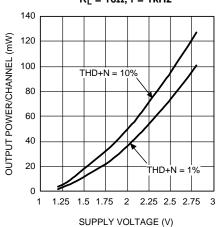


Figure 12.

## Supply Current vs Supply Voltage No Load

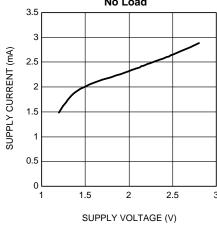
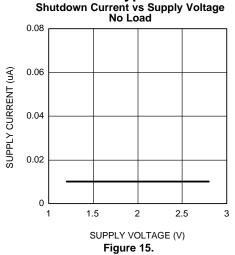


Figure 14.





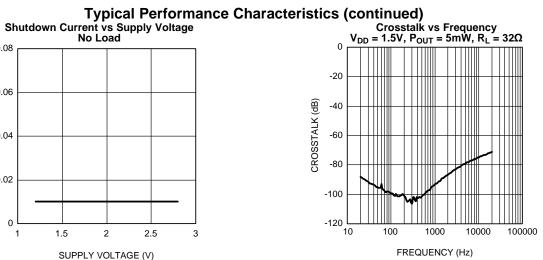


Figure 16.



#### APPLICATION INFORMATION

#### **GENERAL AMPLIFIER FUNCTION**

The LM48861 headphone amplifier features Tl's ground referenced architecture that eliminates the large DC-blocking capacitors required at the outputs of traditional headphone amplifiers. A low-noise inverting charge pump creates a negative supply ( $CPV_{SS}$ ) from the positive supply voltage ( $V_{DD}$ ). The headphone amplifiers operate from these bipolar supplies, with the amplifier outputs biased about GND, instead of a nominal DC voltage (typically  $V_{DD}/2$ ), like traditional amplifiers. Because there is no DC component to the headphone output signals, the large DC-blocking capacitors (typically 220 $\mu$ F) are not necessary, conserving board space and system cost, while improving frequency response.

#### **COMMON MODE SENSE**

The LM48861 features a ground (common mode) sensing feature. In noisy applications, or where the headphone jack is used as a line out to other devices, noise pick up and ground imbalance can degrade audio quality. The LM48861 COM input senses and corrects any noise at the headphone return, or any ground imbalance between the headphone return and device ground, improving audio reproduction. Connect COM directly to the headphone return terminal of the headphone jack Figure 17. No additional external components are required. Connect COM to GND if the common-mode sense feature is not in use.

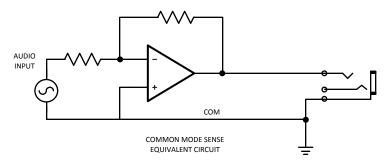


Figure 17.

#### MICRO POWER SHUTDOWN

The voltage applied to the shutdown  $(\overline{SHDN})$  pin controls the LM48861's shutdown function. Activate micropower shutdown by applying a logic-low voltage to the  $\overline{SHDN}$  pin. When active, the LM48861's micro-power shutdown feature turns off the amplifier's bias circuitry, reducing the supply current. The trigger point is 0.4V (max) for a logic-low level, and 1.4V (min) for a logic-high level. The low  $0.1\mu$ A (typ) shutdown current is achieved by applying a voltage that is as near as ground as possible to the  $\overline{SHDN}$  pin. A voltage that is higher than ground may increase the shutdown current.

There are a few ways to control the micro-power shutdown. These include using a single-pole, single-throw switch, a microprocessor, or a microcontroller. When using a switch, connect an external  $100k\Omega$  pull-up resistor between the SHDN pin and GND. Connect the switch between the SHDN pin and  $V_{DD}$ . Select normal amplifier operation by closing the switch. Opening the switch connects the SHDN pin to ground, activating micro-power shutdown. The switch and resistor ensure that the SHDN pin will not float. This prevents unwanted state changes. In a system with a microprocessor or microcontroller, use a digital output to apply the control voltage to the SHDN pin. Driving the SHDN pin with active circuitry eliminates the pull-up resistor.

#### **POWER DISSIPATION**

Power dissipation is a major concern when using any power amplifier, especially one in mobile devices. In the LM48861, the power dissipation comes from the charge pump and two operational amplifiers. Refer to the Figure 10 Power Dissipation vs Output Power curve in the Typical Performance Characteristics section of the datasheet to find the power dissipation associated the output power level of the LM48861. The power dissipation should not exceed the maximum power dissipation point of the DSBGA package given in Equation 1.

$$P_{DMAX} = (T_{JMAX} - T_A) / (\theta_{JA})$$
 (1)



For the LM48861TM DSBGA package,  $\theta_{JA} = 70^{\circ}\text{C/W}$ .  $T_{JMAX} = 150^{\circ}\text{C}$ , and  $T_{A}$  is the ambient temperature of the system surroundings.

#### PROPER SELECTION OF EXTERNAL COMPONENTS

#### Power Supply Bypassing/Filtering

Proper power supply bypassing is critical for low noise performance and high PSRR. Place the supply bypass capacitors as close to the supply pins as possible. Place a  $1\mu F$  ceramic capacitor from  $V_{DD}$  to GND. Additional bulk capacitance may be added as required.

#### **Charge Pump Capacitor Selection**

Use low ESR ceramic capacitors (less than  $100m\Omega$ ) for optimum performance.

#### **Charge Pump Flying Capacitor (C5)**

The flying capacitor (C5) affects the load regulation and output impedance of the charge pump. A C5 value that is too low results in a loss of current drive, leading to a loss of amplifier headroom. A higher valued C5 improves load regulation and lowers charge pump output impedance to an extent. Above  $2.2\mu F$ , the  $R_{DS(ON)}$  of the charge pump switches and the ESR of C5 and C6 dominate the output impedance. A lower value capacitor can be used in systems with low maximum output power requirements.

#### **Charge Pump Hold Capacitor (C6)**

The value and ESR of the hold capacitor (C6) directly affects the ripple on CPV<sub>SS</sub>. Increasing the value of C6 reduces output ripple. Decreasing the ESR of C6 reduces both output ripple and charge pump output impedance. A lower value capacitor can be used in systems with low maximum output power requirements.

#### Power Supply Bypassing /Filtering

Proper power supply bypassing is critical for low noise performance and high PSRR. Place the supply bypass capacitors as close to the device as possible. Typical applications employ a voltage regulator with  $10\mu F$  and  $0.1\mu F$  bypass capacitors that increase supply stability. These capacitors do not eliminate the need for bypassing of the LM48861 supply pins. A  $1\mu F$  capacitor is recommended.

#### Input Capacitor Selection

The LM48861 requires input coupling capacitors. Input capacitors block the DC component of the audio signal, eliminating any conflict between the DC component of the audio source and the bias voltage of the LM48861. The input capacitors create a high-pass filter with the input resistors  $R_{IN}$ . The -3dB point of the high-pass filter is found using Equation 2 below.

$$f = 1 / 2\pi R_{IN}C_{IN}$$

Where

• the value of R<sub>IN</sub> is selected based on the gain-setting resistor selection.

(2)

In relation to Figure 1,  $R_{IN} = R1 = R2$ ,  $C_{IN} = C1 = C2$ .

The input capacitors can also be used to remove low frequency content from the audio signal. Small speakers can not reproduce, and may even be damaged by low frequencies. High-pass filtering the audio signal helps protect the speakers. When the LM48861 is using a single-ended source, power supply noise on the ground is seen as an input signal. Setting the high-pass filter point above the power supply noise frequencies, 217Hz in a GSM phone, for example, filters out the noise such that it is not amplified and heard on the output. Capacitors with a tolerance of 10% or better are recommended for impedance matching and improved CMRR and PSRR.

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#### **PCB Layout Guidelines**

Minimize trace impedance of the power, ground and all output traces for optimum performance. Voltage loss due to trace resistance between the LM48861 and the load results in decreased output power and efficiency. Trace resistance between the power supply and ground has the same effect as a poorly regulated supply, increased ripple and reduced peak output power. Use wide traces for power supply inputs and amplifier outputs to minimize losses due to trace resistance, as well as route heat away from the device. Proper grounding improves audio performance, minimizes crosstalk between channels and prevents switching noise from interfering with the audio signal. Use of power and ground planes is recommended.

As described in the Common Mode Sense section, the LM48861 features a ground sensing feature. On the PCB layout, connect the COM pin (pin D2) directly to the headphone jack ground and also to the left and right input grounds. This will help correct any noise or any ground imbalance between the headphone return, input, and the device ground, therefore improving audio reproduction.

The charge pump capacitors and traces connecting the capacitor to the device should be kept away from the input and output traces to avoid any switching noise injected into the input or output.

#### **Demo Board Schematic and Layout**

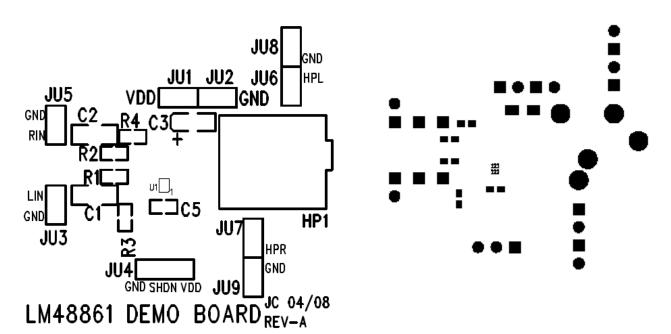


Figure 18. Top Silkscreen Layer

Figure 19. Top Solder Mask



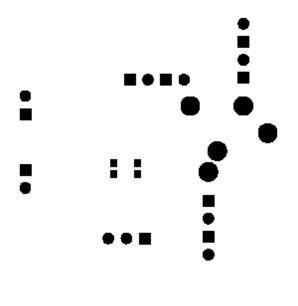


Figure 20. Bottom Solder Mask

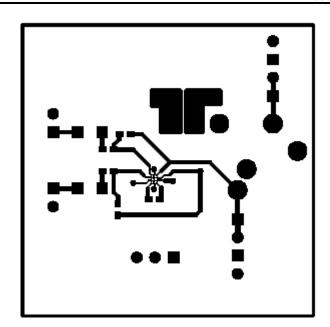


Figure 21. Top Layer

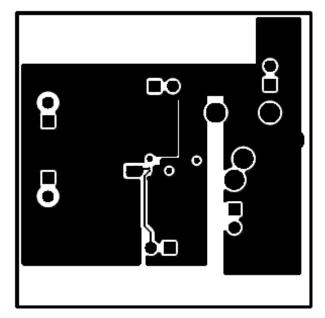


Figure 22. Layer 2

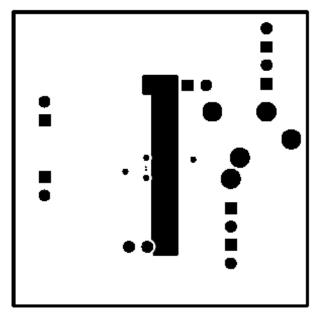


Figure 23. Layer 3



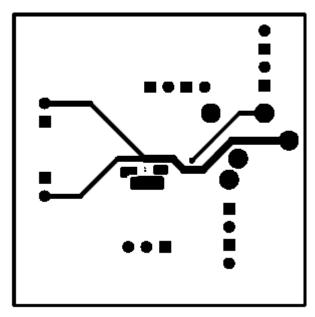


Figure 24. Bottom Layer



551600087-001 REV-B

Figure 25. Bottom Silkscreen



#### **REVISION HISTORY**

Rev	Date	Description
1.0	06/11/08	Initial release.
1.01	02/08/10	Input text edits.
В	05/02/2013	Changed layout of National Data Sheet to TI format.

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#### **PACKAGING INFORMATION**

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
LM48861TM/NOPB	Active	Production	DSBGA (YFQ)   12	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	G
									K3
LM48861TM/NOPB.A	Active	Production	DSBGA (YFQ)   12	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	G
									K3

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

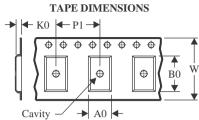
<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM48861TM/NOPB	DSBGA	YFQ	12	250	178.0	8.4	1.35	1.75	0.76	4.0	8.0	Q1

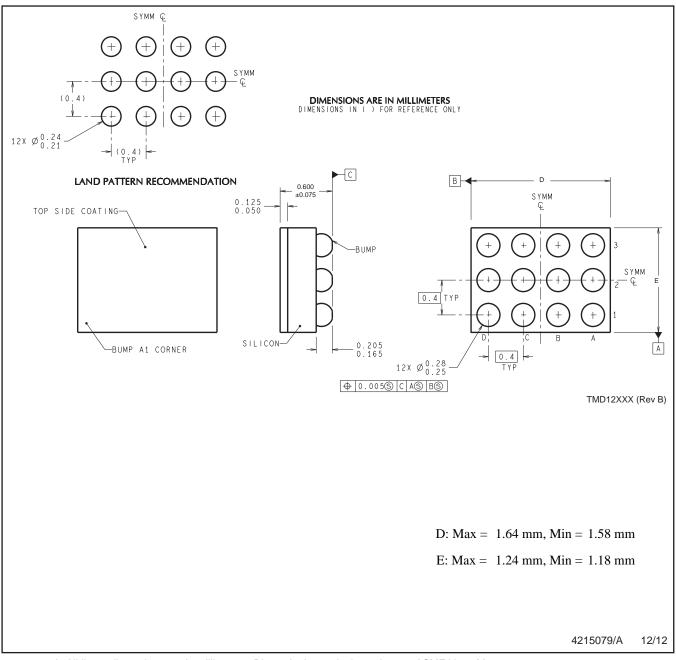
## **PACKAGE MATERIALS INFORMATION**

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#### \*All dimensions are nominal

Ì	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ı	LM48861TM/NOPB	DSBGA	YFQ	12	250	208.0	191.0	35.0



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

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